UNIVERSITY OF CAMBRIDGE INTERNATIONAL EXAMINATIONS International General Certificate of Secondary Education

## www.papacambridge.com MARK SCHEME for the October/November 2009 question paper

## for the guidance of teachers

## 0445 DESIGN AND TECHNOLOGY

0445/04

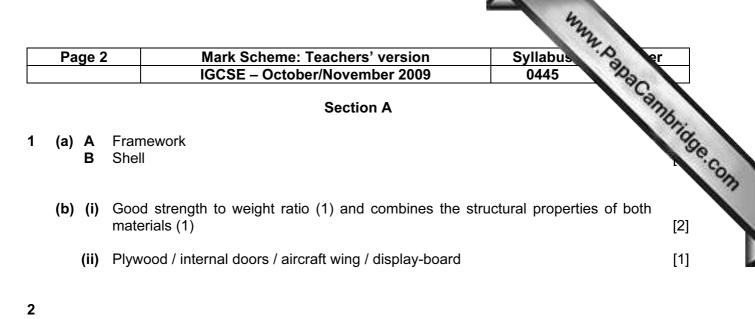
Paper 4 (Technology), maximum raw mark 50

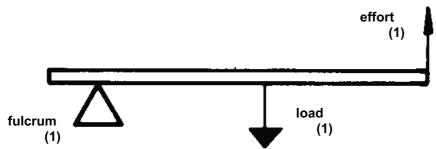
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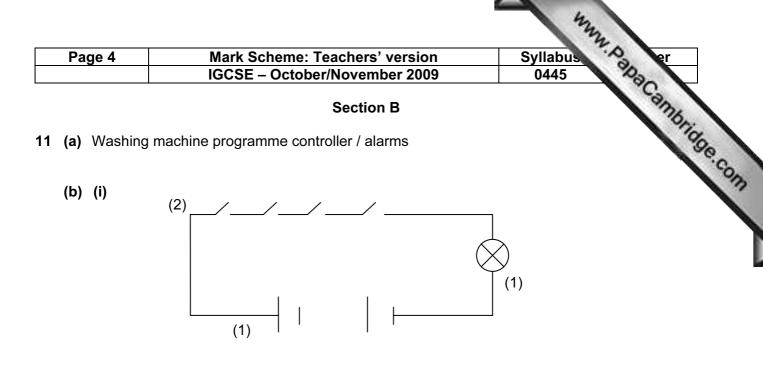


3 Complete the table showing a selection of electrical switches.

Туре	Appearance	Application
REED (1)		Non-contact operation by magnet for detecting the opening or closing of doors/windows
Tilt	H	DETECTS MOVEMENT (1)
Membrane panel		Waterproof keypads

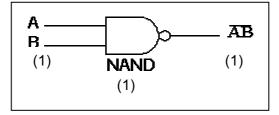
[3]

	Page 3	Mark Scheme: Teachers' version IGCSE – October/November 2009	Syllabus Pr 0445
4	(a)	(1) ORP12	Syllabus 0445 0445 Syllabus 045 Syllabus 045 Sy
		(1)	[2]
	(b) Burglar ala	rm / movement detection / light level alarm	[1]
5		ne driven gear = speed of driver × gear ratio (R) on driver / Teeth on driven = 18 / 12 (1)	
		00 × 3 / 2 = 300 rpm (1)	[3]
	(b) Add an idle	er gear (1) between the driver and driven gears (1)	[2]
	OR		[1]
,	Cantilever		[1]
;	First		[1]
1	Drilling machine / lathe		[1]
0	Reduce friction / reduce wear and tear / energy efficiency		[1]



[4]

(ii) Sketch the circuit symbol for a NAND gate.

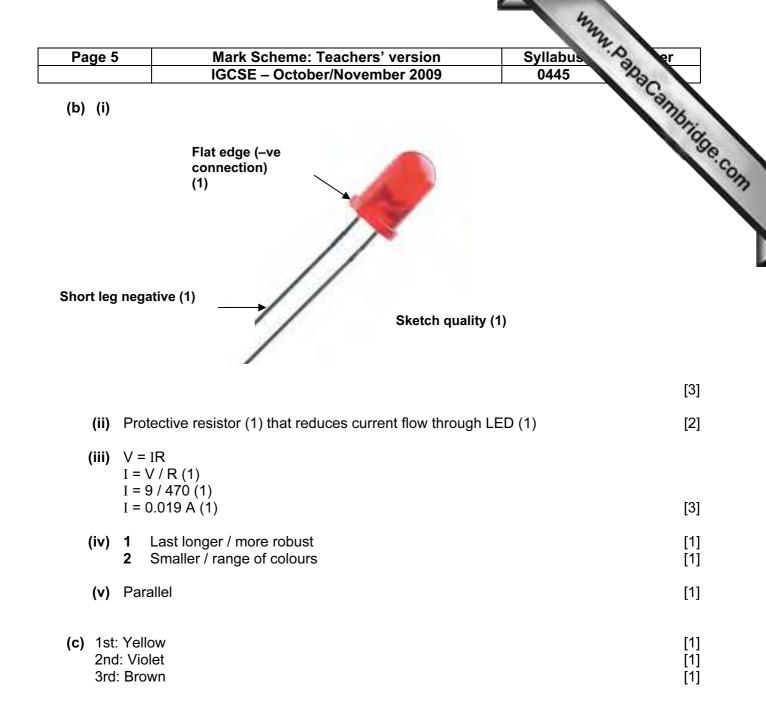


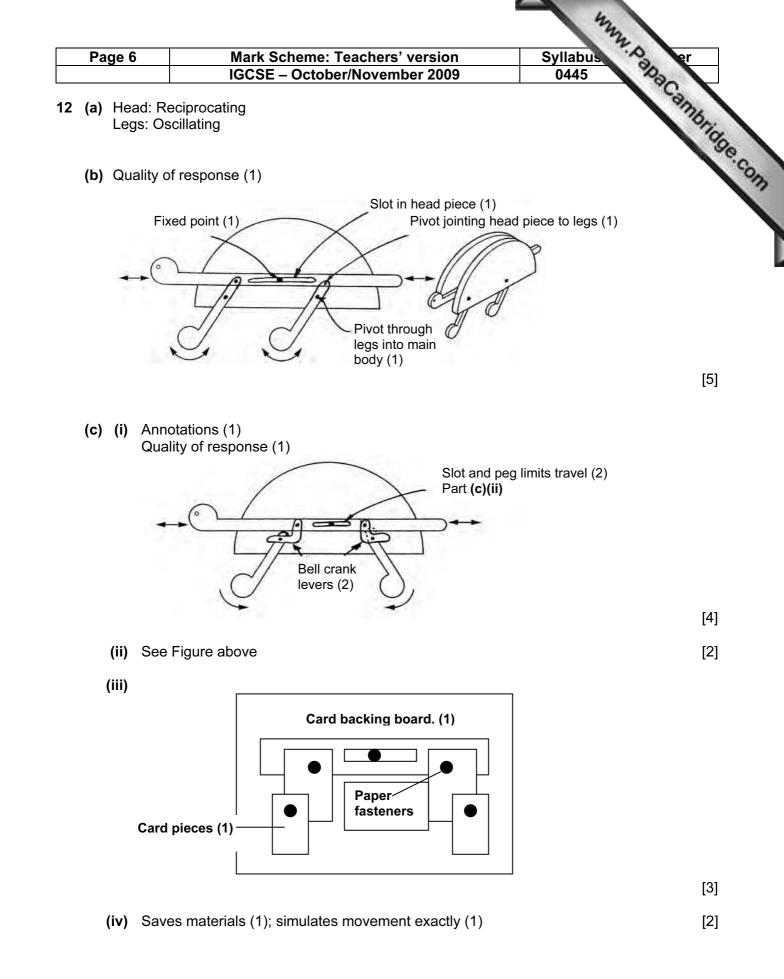
(iii) Complete the truth table below for a NAND gate.

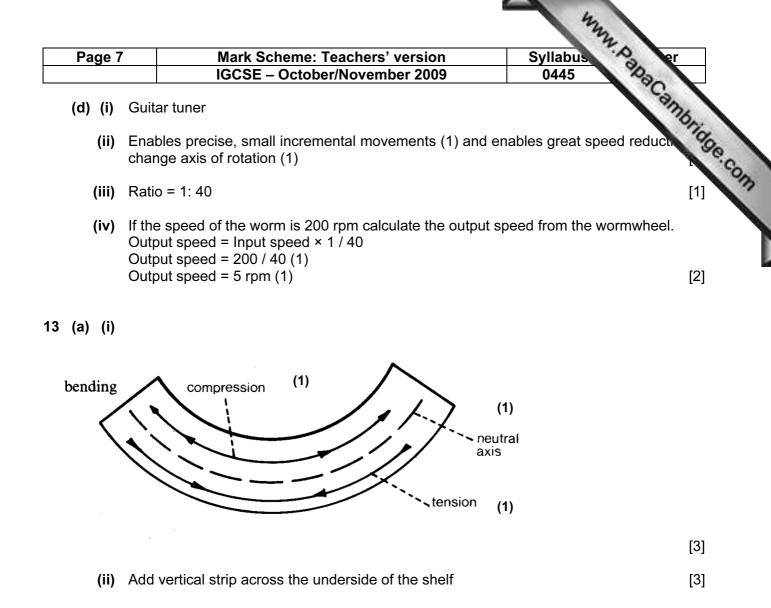
Input A	Input B	Output
0	0	1
0	1	1
1	0	1
1	1	0

[3]

[3]

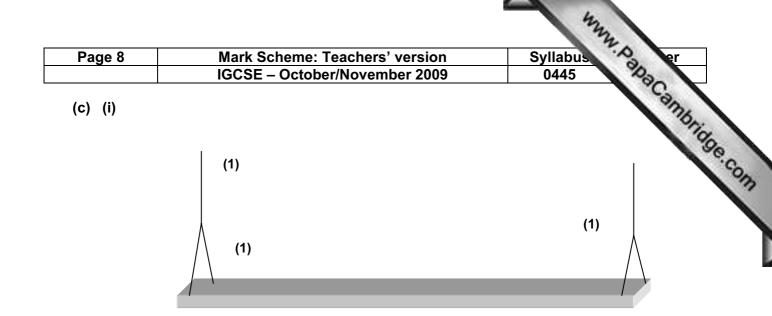






(b) Reactions at L and R.  
R + L = 30 N  
R × 1.2 = 
$$(0.25 \times 10) + (0.55 \times 15) + (0.95 \times 5) (1)$$
  
R =  $\frac{2.5 + 8.25 + 4.75}{1.25}$  (1)  
R = 12.92 N (1)  
L = 30N - 12.92 N = 17.08 N (1)

[4]

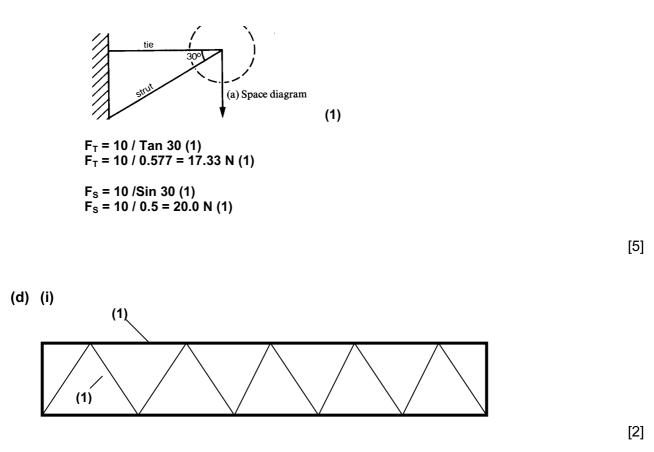


[3]

[2]

- (ii) Tension / Tensile [1]
- (iii) All internal forces (1) are balanced by all external forces (1)

(iv)



(ii) Good strength to weight ratio (1) and a low cost material (1) that can be recycled (1) [3]